

Features

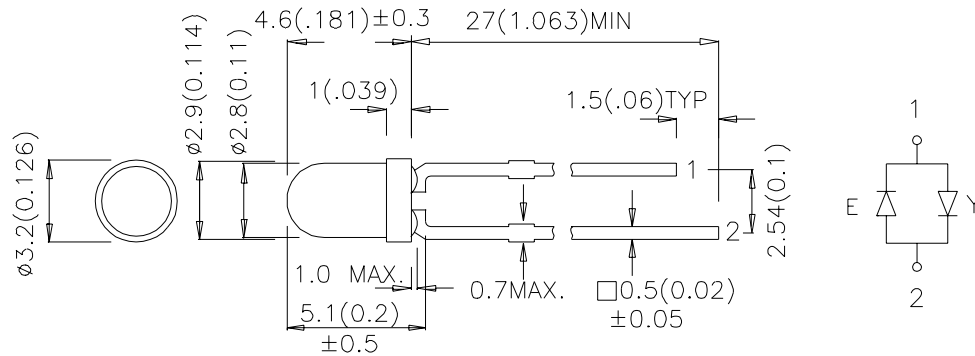
- UNIFORM LIGHT OUTPUT.
- LOW POWER CONSUMPTION.
- I.C. COMPATIBLE.
- LONG LIFE - SOLID STATE RELIABILITY.

Description

The High Efficiency Red source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Orange Light Emitting Diode.

The Yellow source color devices are made with Gallium Arsenide Phosphide on Gallium Phosphide Yellow Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 20 mA		Viewing Angle
			Min.	Typ.	2θ1/2
W937EYW	HIGH EFFICIENCY RED (GaAsP/GaP)	WHITE DIFFUSED	7	20	60°
	YELLOW (GaAsP/GaP)		4	7	

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at T_A=25°C

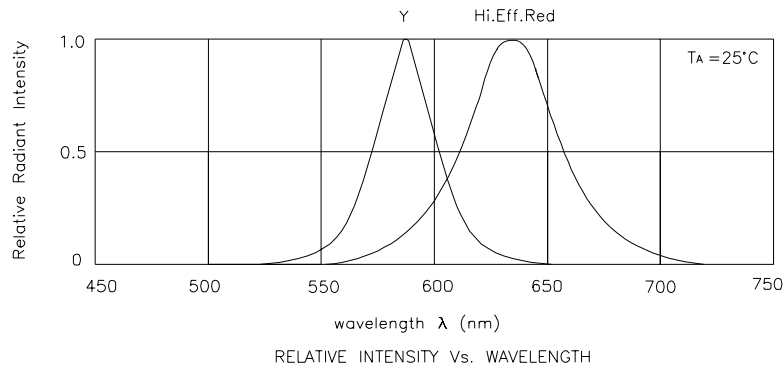
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
λ _{peak}	Peak Wavelength	High Efficiency Red Yellow	627 590		nm	I _F =20mA
λ _D	Dominate Wavelength	High Efficiency Red Yellow	625 588		nm	I _F =20mA
Δλ _{1/2}	Spectral Line Half-width	High Efficiency Red Yellow	45 35		nm	I _F =20mA
C	Capacitance	High Efficiency Red Yellow	15 20		pF	V _F =0V;f=1MHz
V _F	Forward Voltage	High Efficiency Red Yellow	2.0 2.1	2.5 2.5	V	I _F =20mA

Absolute Maximum Ratings at T_A=25°C

Parameter	High Efficiency Red	Yellow	Units
Power dissipation	105	105	mW
DC Forward Current	30	30	mA
Peak Forward Current [1]	160	140	mA
Operating/Storage Temperature	-40°C To +85°C		
Lead Solder Temperature [2]	260°C For 5 Seconds		

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.
2. 2mm below package base.



High Efficiency Red/Yellow

W937EYW

